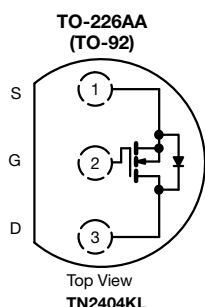


# N-Channel 240 V (D-S) MOSFET

## PRODUCT SUMMARY

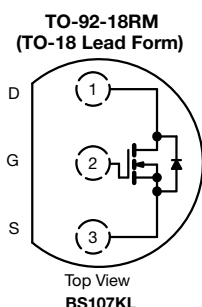
Part Number	V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	V <sub>GS(th)</sub> (A)	I <sub>D</sub> (A)	Q <sub>g</sub> (Typ.)
TN2404K	240	4 at V <sub>GS</sub> = 10 V	0.8 to 2	0.2	4.87 nC
TN2404K, BS107KL				0.3	



Device Marking Front View

"S" TN  
2404KL  
xxyy

"S" = Siliconix Logo  
xxyy = Date Code



Device Marking Front View

"S" BS  
107KL  
xxyy

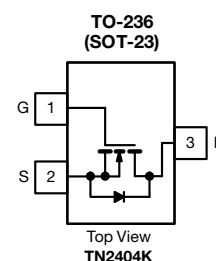
"S" = Siliconix Logo  
xxyy = Date Code

## FEATURES

- Low On-Resistance: 4 Ω
- Secondary Breakdown Free: 260 V
- Low Power/Voltage Driven
- Low Input and Output Leakage
- Excellent Thermal Stability
- Material categorization:  
For definitions of compliance please see  
[www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

## APPLICATIONS

- High-Voltage Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Transistors, etc.
- Telephone Mute Switches, Ringer Circuits
- Power Supply, Converters
- Motor Control



## BENEFITS

- Low Offset Voltage
- Full-Voltage Operation
- Easily Driven Without Buffer
- Low Error Voltage
- No High-Temperature "Run-Away"

Marking Code: K1ywl  
K1 = Part Number Code for TN2404K  
y = Year Code  
w = Week Code  
l = Lot Traceability

## ORDRING INFORMATION

Standard Partnumber	Ordering Part Number	Option
TN2404K	TN2404K-T1-E3	Lead (Pb) free
	TN2404K-T1-GE3	Lead (Pb) free and Halogen free
TN2404KL	TN2404KL-TR1-E3	With Tape and Reel Spool Option
BS107KL	BS107KL-TR1-E3	

## ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25 °C, unless otherwise noted)

Parameter		Symbol	TN2404K	TN2404KL/BS107KL	Symbol
Drain-Source Voltage		V <sub>DS</sub>	240		V
Gate-Source Voltage		V <sub>GS</sub>	± 20		
Continuous Drain Current (T <sub>J</sub> = 150 °C)	T <sub>A</sub> = 25 °C	I <sub>D</sub>	0.2	0.3	A
	T <sub>A</sub> = 70 °C		0.16	0.25	
Pulsed Drain Current (t = 300 μs)		I <sub>DM</sub>	0.8	1.4	
Maximum Power Dissipation	T <sub>A</sub> = 25 °C	P <sub>D</sub>	0.36	0.8	W
	T <sub>A</sub> = 70 °C		0.23	0.51	
Thermal Resistance Junction-to-Ambient		R <sub>thJA</sub>	350 <sup>b</sup>	156	°C/W
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C

Notes:

a. Pulse width limited by maximum junction temperature.

b. Surface mounted on an FR4 board.

**SPECIFICATIONS** ( $T_A = 25\text{ }^{\circ}\text{C}$ , unless otherwise noted)

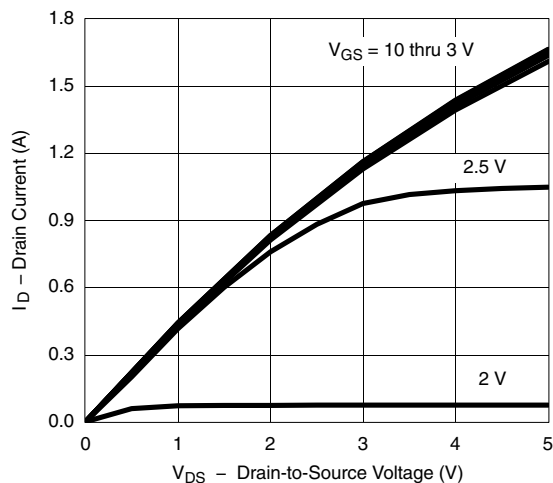
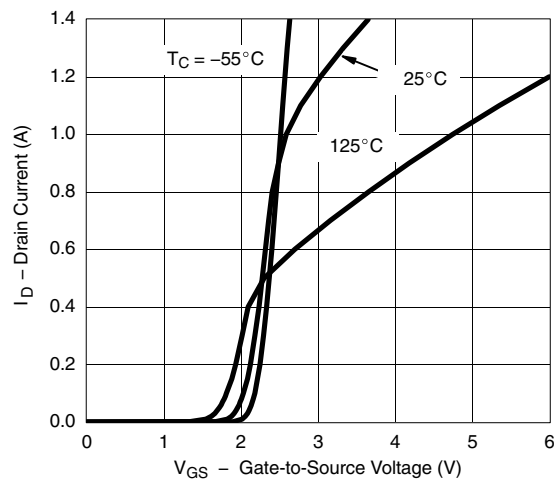
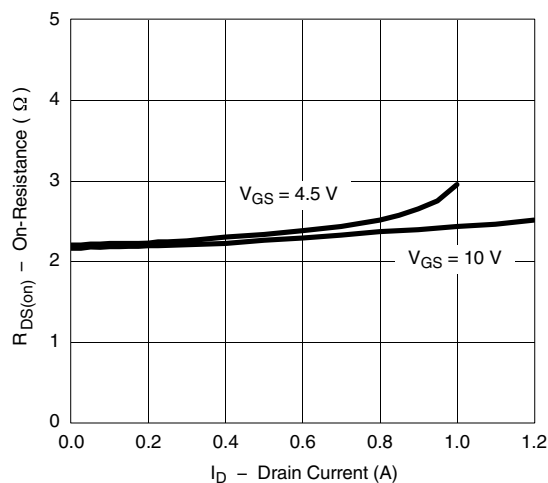
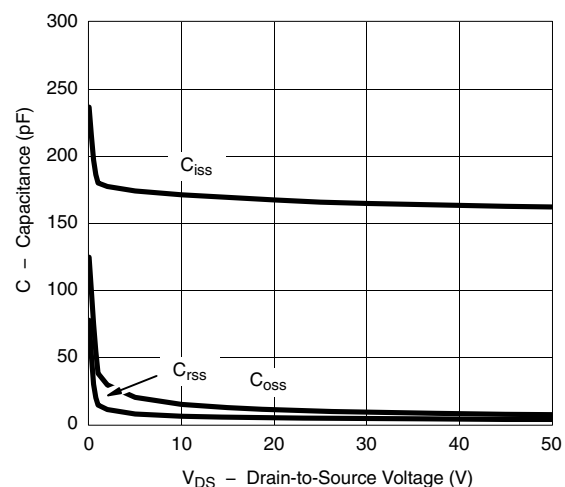
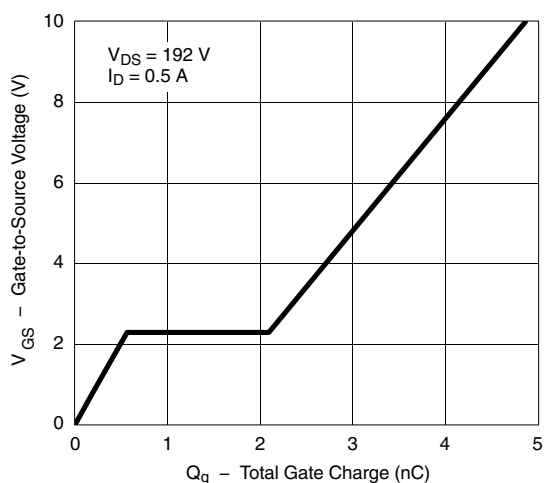
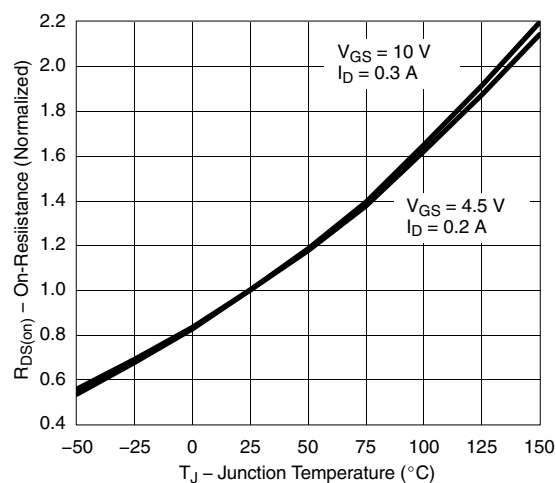
Parameter	Symbol	Test Conditions	Limits			
			Min.	Typ. <sup>a</sup>	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V <sub>DS</sub>	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 100 μA	240	257		V
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA	0.8	1.65	2	
Gate-Source Leakage	I <sub>GSS</sub>	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ± 20 V			± 100	nA
Zero Gate Voltage Drain Current	I <sub>BSS</sub>	V <sub>DS</sub> = 192 V, V <sub>GS</sub> = 0 V			1	μA
		V <sub>DS</sub> = 192 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55 °C			10	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 10 V	0.8			A
		V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 4.5 V	0.5			
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 0.3 A		2.2	4	Ω
		V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 0.2 A		2.3	4	
		V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 0.1 A		2.4	6	
Forward Transconductance <sup>a</sup>	g <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.3 A		1.6		S
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 0.3 A		0.8	1.2	V
Dynamic <sup>b</sup>						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> = 192 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 0.5 A		4.87	8	nC
Gate-Source Charge	Q <sub>gs</sub>			0.56		
Gate-Drain Charge	Q <sub>gd</sub>			1.53		
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 60 V, R <sub>L</sub> = 200 Ω I <sub>D</sub> ≅ 0.3 A, V <sub>GEN</sub> = 10 V, R <sub>g</sub> = 25 Ω		5	10	ns
Rise Time	t <sub>r</sub>			12	20	
Turn-Off Delay Time	t <sub>d(off)</sub>			35	60	
Fall Time	t <sub>f</sub>			16	25	

Notes:

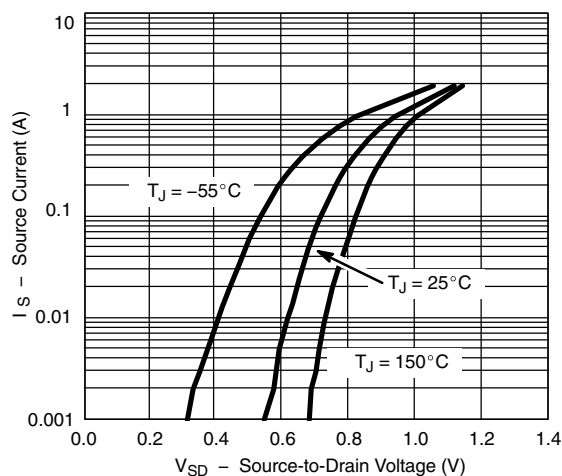
a. Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ 

b. Guaranteed by design, not subject to production testing.

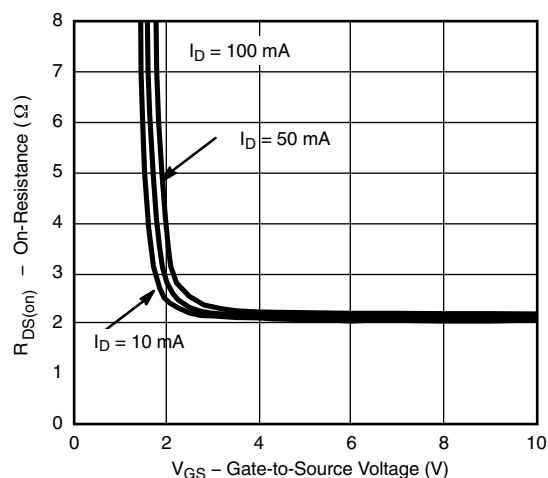
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**TYPICAL CHARACTERISTICS** (25 °C, unless otherwise noted)

**Output Characteristics**

**Transfer Characteristics**

**On-Resistance vs. Drain Current**

**Capacitance**

**Gate Charge**

**On-Resistance vs. Junction Temperature**

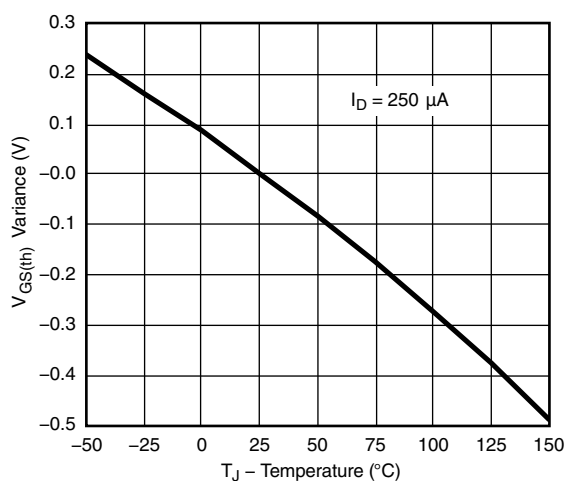
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



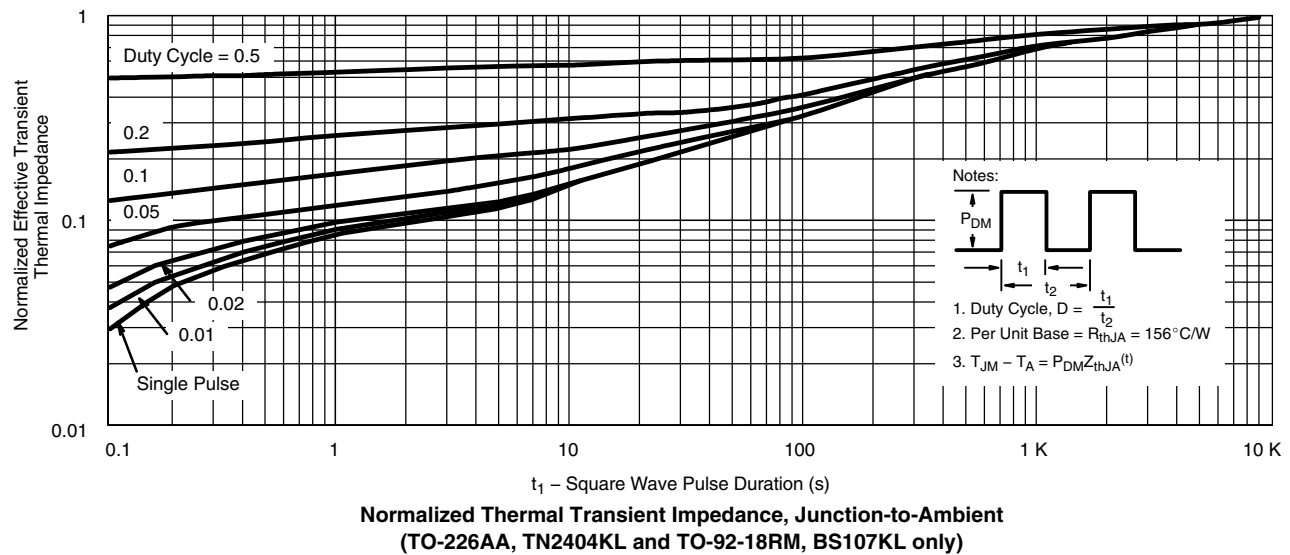
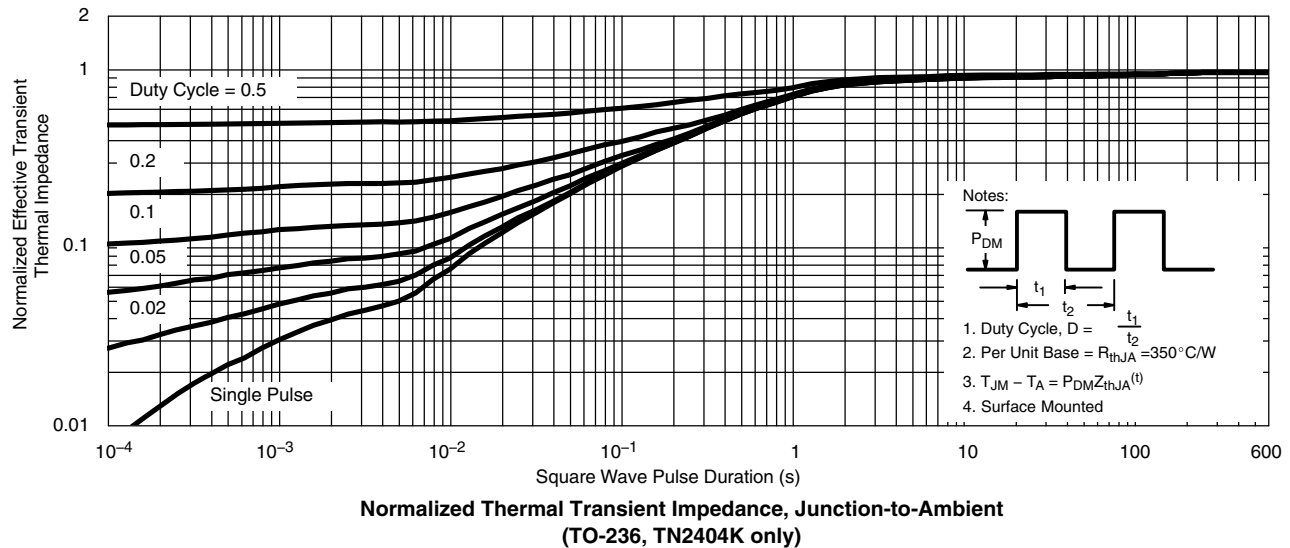
Source-Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage

**TYPICAL CHARACTERISTICS** (25 °C, unless otherwise noted)

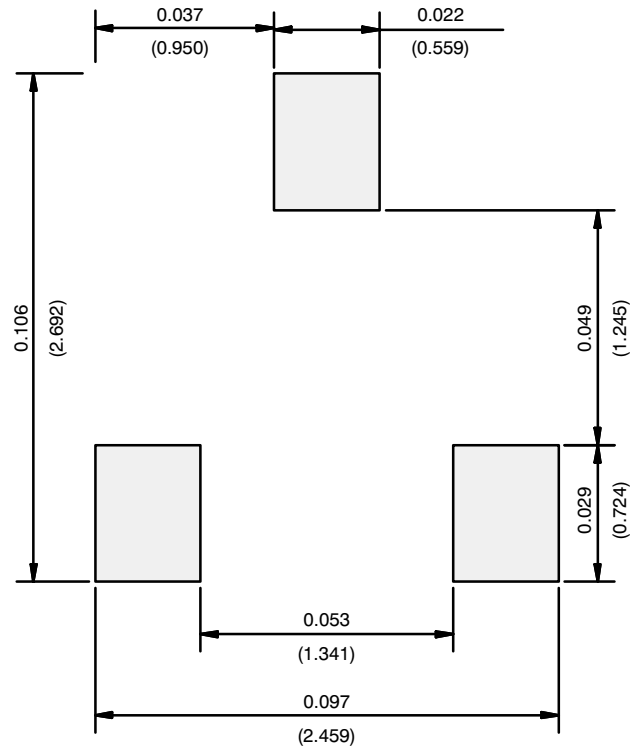
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## SOT-23 (TO-236): 3-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	0.89	1.12	0.035	0.044
A <sub>1</sub>	0.01	0.10	0.0004	0.004
A <sub>2</sub>	0.88	1.02	0.0346	0.040
b	0.35	0.50	0.014	0.020
c	0.085	0.18	0.003	0.007
D	2.80	3.04	0.110	0.120
E	2.10	2.64	0.083	0.104
E <sub>1</sub>	1.20	1.40	0.047	0.055
e	0.95 BSC		0.0374 Ref	
e <sub>1</sub>	1.90 BSC		0.0748 Ref	
L	0.40	0.60	0.016	0.024
L <sub>1</sub>	0.64 Ref		0.025 Ref	
S	0.50 Ref		0.020 Ref	
q	3°	8°	3°	8°
ECN: S-03946-Rev. K, 09-Jul-01				
DWG: 5479				

## RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads  
Dimensions in Inches/(mm)

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